TCXO2012S-UHS-xx.xxxMHz-A-B-C-D

Ultra-stable TCXO with OCXO type stability

DEI Releases New Ultra-High Stability (UHS) TCXO's

The Ultra-High Stability (UHS) TCXO family is based on the latest proprietary compensation algorithms that take full advantage of precision crystal manufacturing process breakthroughs to deliver OCXO-like stability at a fraction of the power consumption.

Better than +/- 100 ppb stability can be maintained over an extended temperature range of -40C to +105C. Better than +/- 50 ppb can be offered over -40C to +85C.

High performance small cell base stations, mobile radio manpacks, and SATCOM reference clocks are ideal applications for this cutting edge TCXO design and process technology.

Please consult with sales for any custom requirements. sales@dynamiceng.com

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Features and Benefits

Ultra High Precision; ±100ppb for -40°C to +105°C

±50ppb for -40°C to +85°C 14 pin DIP package footprint

Sealed Crystal Package; Sealed Oscillator Package

Typical Applications

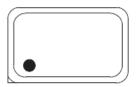
Small Cell Base Stations
High Performance Mobile Radio Manpack
SATCOM clock reference

Mechanical Drawing & Pin Connections

Drawing No:MD170003-1

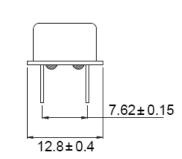
Side View



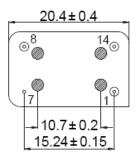


Pin1 Symbol

7.8 MAX 0.8 6.4 ± 0.5



Bottom View



Pin#	Function			
1	VCON			
7	GND			
8	Output			
14	VDD			

Unit: mm

1mm=0.0394inch

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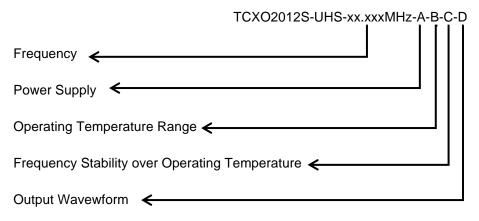
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Specifications

Oscillator	O and Hillians	5.	0V	3.	3V	Unit	Note
Specification	Condition	Min.	Max.	Min.	Max.		
Frequency Range		10.00	40.00	10.00	40.00		
Standard Frequency		10.00, 12.80,19.2,19.44, 20.00, 26.00			MHz		
RF Output						•	
Output Wave Form	Clipped Sine Wave	0.8	-	0.8	-	Vp-p	
Output Level							
Output High (Logic "1")	CMOS	3.50	-	2.31	-	V	
Output Low (Logic "0")	CIVIOS	-	1.50	-	0.99	V	
Duty		45	55	45	55	%	
Start Time		-	2	-	2	mSec	
Transition Time:	Measured between 10%	6 nS					
Rise / Fall Time	and 90% or VDD, with					nSec	
Rise / Fall Tillle	an output load of 15pF						
Power Supply							
Supply Voltage Variation	V _{DD} ±5%	4.750	5.250	3.135	3.465	V	
Supply Current		-	15	-	10	mA	
Control Voltage							
Pulling Range		±5.0	-	±5.0	-	ppm	
Frequency Stability							
							1 hour
Frequency Tolerance	Frequency @ +25°C	-	±2.0	-	±2.0	ppm	after
							reflow
Over Temperature	-40°C to +85°C	-	±50	-	±50	ppb	
Over remperature	-20°C to +70°C	-	±30	-	±30	0	
Supply Voltage Change	±5% change	_	±0.02	_	±0.02	ppm	
	2070 onango		20.02		20.02	ррпп	
Aging (@ 1 st year)		_	±1.0	_	±1.0	ppm/	
						year	
Phase Noise						<u> </u>	
	100 Hz offset	-123			dBcHz		
Phase noise @ 10MHz	1 kHz offset	-143 -150					
	10 kHz offset						
Environmental Conditions		1					
Parameter		Reference Std.					
Operating temperature range		-40°C to +85°C or -40°C to +105°C					
Storage temperature range		-55°C to +125°C					

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Ordering Options



Options Codes	Description	Options
xx.xxx	Frequency up to 3 decimals	Standard Frequencies 10.000MHz, 12.800MHz, 19.200MHz, 19.440MHz, 20.000MHz, 26.000MHz
А	Power Supply	1 = +5V 2 = +3.3V
В	Operating Temperature Range	1 = -40°C to +105°C 2 = -40°C to +85°C
С	Frequency Stability Over Operating Temperature	1 = ±100ppb 2 = ±50ppb**Note: ±50ppb available only with -40°C to +85°C
D	Output Waveform	1 = CMOS 2 = Clipped Sine Wave

Example: TCXO2012S-UHS-19.440MHz-1-2-2-1

Frequency = 19.440MHz

Power Supply = 5V

Operating Temperature Range = -40°C to +85°C

Frequency Stability Over Operating Temperature = ±50ppb

Output Waveform = CMOS